NSN 5961-01-339-4247

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-339-4247 **Inclosure Material:** Metal **Overall Length:** Between 0.160 inches and 0.180 inches **Terminal Length:** Between 0.500 inches and 0.750 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Function For Which Designed:** Rectifier Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-205af **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 54.0 nonrepetitive peak reverse voltage and 45.0 working peak reverse voltage and 45.0 repetitive peak reverse voltage and 45.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 3.60 amperes forward current, average absolute and 80.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

Mil-std (military Standard):

Mil-prf-19500 spec.

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